## NSN 5962-01-159-6501

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View Online at https://aerobasegroup.com/nsn/5962-01-159-6501 **Body Length:** 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.210 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** Glcm bgm-109 **Features Provided:** Hermetically sealed and burn in and ultraviolet erasable and programmable and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 11.5 volts power source **Time Rating Per Chacteristic:** 600.00 nanoseconds propagation delay time, low to high level output and 600.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life:

**Demilitarization:** Yes - demil/mli

**Unit Of Measure:** 

N/a

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